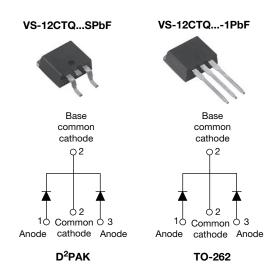
VS-12CTQ...SPbF, VS-12CTQ...-1PbF Series

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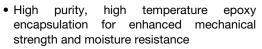
High Performance Schottky Rectifier, 2 x 6 A



PRODUCT SUMMARY					
Package	D ² PAK, TO-262				
I _{F(AV)}	2 x 6 A				
V_{R}	35 V, 40 V, 45 V				
V _F at I _F	0.53 V				
I _{RM}	7 mA at 125 °C				
T _J max.	175 °C				
Diode variation	Common cathode				
E _{AS}	8 mJ				

FEATURES

- 175 °C T_J operation
- Center tap TO-220 package
- Low forward voltage drop





- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-12CTQ... center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	12	А			
V _{RRM}	Range	35 to 45	V			
I _{FSM}	t _p = 5 µs sine	690	А			
V _F	6 A _{pk} , T _J = 125 °C (per leg)	0.53	V			
T _J	Range	-55 to +175	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-12CTQ035SPbF VS-12CTQ035-1PbF	VS-12CTQ040SPbF VS-12CTQ040-1PbF	VS-12CTQ045SPbF VS-12CTQ045-1PbF	UNITS	
Maximum DC reverse voltage	V_R	35	40	45	V	
Maximum working peak reverse voltage	V_{RWM}	33	40	45	V	



VS-12CTQ...SPbF, VS-12CTQ...-1PbF Series

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ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONI	DITIONS	VALUES	UNITS	
Maximum average per leg		I _{F(AV)}	50 % duty cycle at T _C = 160 °C, rectangular waveform		6		
See fig. 5	forward current See fig. 5 per device				12	Α	
Maximum peak one cyc			5 μs sine or 3 μs rect. pulse	Following any rated load	690	_	
non-repetitive surge current per leg See fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	140	А	
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 1.20 A, L = 11.10 mH		8	mJ	
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.20	Α	

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		6 A	T _{.1} = 25 °C	0.60	
Maximum forward voltage drop per leg See fig. 1	V (1)	12 A	1j=25 C	0.73	V
	V _{FM} ⁽¹⁾	6 A	T 405.00	0.53	
		12 A	- T _J = 125 °C	0.64	
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V Dataday	0.8	mA
See fig. 2		T _J = 125 °C	V _R = Rated V _R	7.0	
Threshold voltage	$V_{F(TO)}$	T T manyimay ma	•	0.35	V
Forward slope resistance	r _t	$T_J = T_J$ maximum		18.23	mΩ
Maximum junction capacitance per leg	C_T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		400	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{^{(1)}}$ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHAN	IICAL SPE	CIFICAT	IONS			
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storag temperature range	е	T _J , T _{Stg}		-55 to +175	°C	
Maximum thermal resistance, junction to case per leg		- R _{thJC}	DC operation See fig. 4	3.50		
Maximum thermal resistance, junction to case per package		1 thJC	DC operation	1.75	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50		
Approximate weight	Approximate weight			2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf · cm	
Wounting torque	maximum			12 (10)	(lbf · in)	
				12CTC	Q035S	
			Case style D ² PAK	12CTC	Q040S	
					Q045S	
Marking device	warking device			12CTQ	035-1	
			Case style TO-262	12CTQ	040-1	
				12CTQ	045-1	

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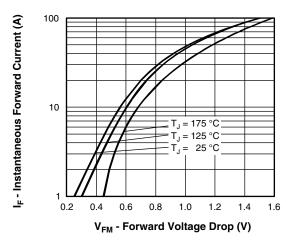


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

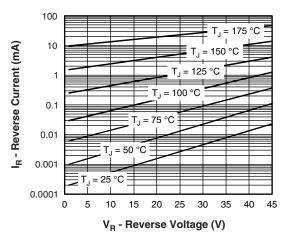


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

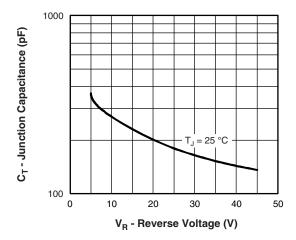


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

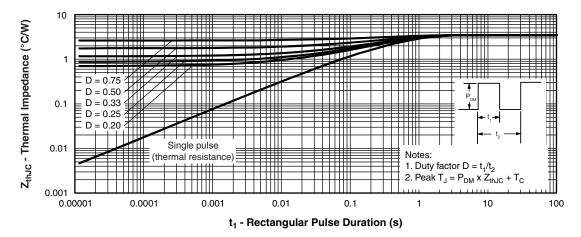


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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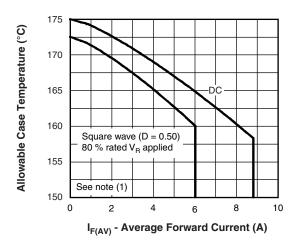


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

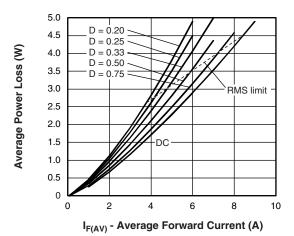


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

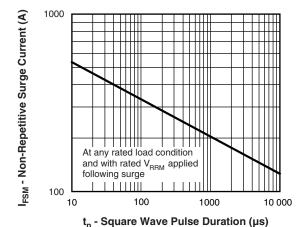


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

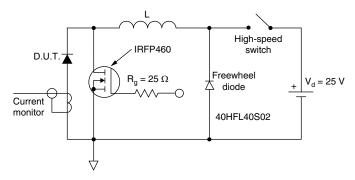


Fig. 8 - Unclamped Inductive Test Circuit

Note

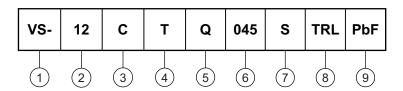
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = 80 \text{ \% rated } V_R \\ \end{array}$

VS-12CTQ...SPbF, VS-12CTQ...-1PbF Series

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Current rating (12 A)

- Circuit configuration: C = common cathode

4 - T = TO-220

5 - Schottky "Q" series

035 = 35 V

Voltage ratings

040 = 40 V

7 - • S = D²PAK

045 = 45 V

• -1 = TO-262

8 - • None = tube

None = tube (50 pieces)
 TRL = tape and reel (left oriented - for D²PAK only)

• TRR = tape and reel (right oriented - for D^2PAK only)

9 - PbF = lead (Pb)-free

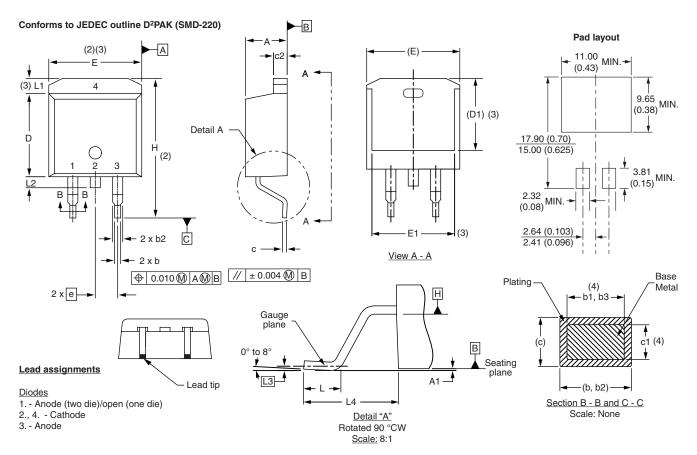
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95014</u>					
Part marking information	www.vishay.com/doc?95008				
Packaging information	www.vishay.com/doc?95032				



Vishay Semiconductors

D²PAK, TO-262

DIMENSIONS - D²PAK in millimeters and inches



	1		1			
SYMBOL	MILLIN	MILLIMETERS		INCHES		
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

(7) Outline conforms to JEDEC outline TO-263AB

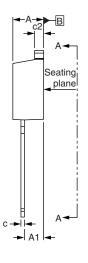
Document Number: 95014 Revision: 31-Mar-09

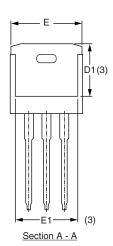
Vishay Semiconductors

D²PAK, TO-262



DIMENSIONS - TO-262 in millimeters and inches





⊕ 0.010 **M** A **M** B

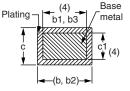
Lead assignments



Diodes

1. - Anode (two die)/open (one die) 2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIMETERS		INC	INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	9.65 0.335		2	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.100	D BSC		
L	13.46	14.10	0.530	0.555		
L1	=	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

Legal Disclaimer Notice



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